

Silicon PIN Photodiode

Version 1.3

SFH 213 FA



Features:

- Wavelength range ($S_{10\%}$) 750 nm to 1100 nm
- Short switching time (typ. 5 ns)
- 5 mm LED plastic package

Applications

- High speed photointerrupters
- Industrial electronics
- For control and drive circuits

Ordering Information

Type:	Photocurrent I_P [μA] $V_R = 5 V, \lambda = 870 nm, E_e = 1 mW/cm^2$	Ordering Code
SFH 213 FA	90 (≥ 65)	Q62702P1671

Maximum Ratings ($T_A = 25\text{ °C}$)

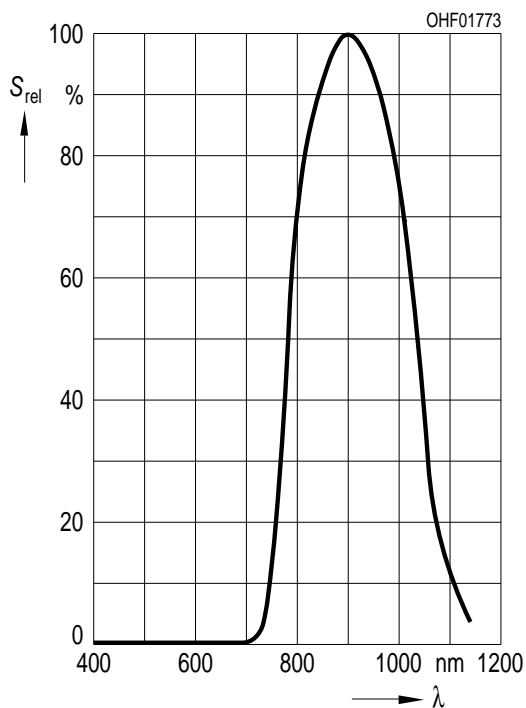
Parameter	Symbol	Values	Unit
Operating and storage temperature range	$T_{op}; T_{stg}$	-40 ... 100	°C
Reverse voltage	V_R	20	V
Reverse voltage ($t < 2\text{ min}$)	V_R	50	V
Total Power dissipation	P_{tot}	150	mW
ESD withstand voltage (acc. to ANSI/ ESDA/ JEDEC JS-001 - HBM)	V_{ESD}	2000	V

Characteristics ($T_A = 25\text{ °C}$)

Parameter	Symbol	Values	Unit
Photocurrent ($V_R = 5\text{ V}$, $\lambda = 870\text{ nm}$, $E_e = 1\text{ mW/cm}^2$)	I_P (typ (min))	90 (≥ 65)	μA
Wavelength of max. sensitivity	$\lambda_{S\text{ max}}$ (typ)	900	nm
Spectral range of sensitivity	$\lambda_{10\%}$ (typ)	(typ) 750 ... 1100	nm
Radiant sensitive area	A (typ)	1.00	mm^2
Dimensions of radiant sensitive area	L x W (typ)	1 x 1	mm x mm
Half angle	φ (typ)	± 10	°
Dark current ($V_R = 20\text{ V}$)	I_R (typ (max))	1 (≤ 5)	nA
Spectral sensitivity of the chip ($\lambda = 870\text{ nm}$)	$S_{\lambda\text{ typ}}$ (typ)	0.65	A / W
Quantum yield of the chip ($\lambda = 870\text{ nm}$)	η (typ)	0.93	Electrons / Photon
Open-circuit voltage ($E_e = 0.5\text{ mW/cm}^2$, $\lambda = 870\text{ nm}$)	V_O (typ (min))	380 (≥ 300)	mV
Short-circuit current ($E_e = 0.5\text{ mW/cm}^2$, $\lambda = 870\text{ nm}$)	I_{SC} (typ)	42	μA
Rise and fall time ($V_R = 20\text{ V}$, $R_L = 50\ \Omega$, $\lambda = 850\text{ nm}$)	t_r, t_f (typ)	0.005	μs
Forward voltage ($I_F = 100\text{ mA}$, $E = 0$)	V_F (typ)	1.3	V
Capacitance ($V_R = 0\text{ V}$, $f = 1\text{ MHz}$, $E = 0$)	C_0 (typ)	11	pF
Temperature coefficient of V_O	TC_V (typ)	-2.6	mV / K

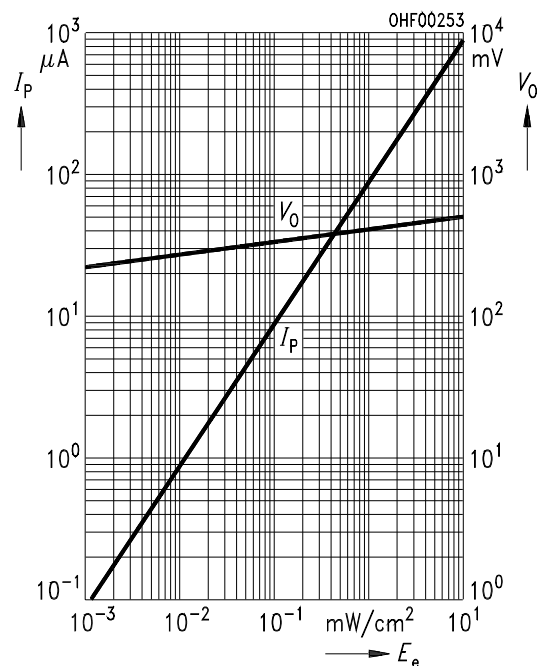
Parameter		Symbol	Values	Unit
Temperature coefficient of I_{SC} ($\lambda = 870 \text{ nm}$)	(typ)	TC_1	0.1	% / K
Noise equivalent power ($V_R = 20 \text{ V}$, $\lambda = 870 \text{ nm}$)	(typ)	NEP	0.028	$\mu\text{W} / \text{Hz}^{1/2}$
Detection limit ($V_R = 20 \text{ V}$, $\lambda = 870 \text{ nm}$)	(typ)	D^*	3.6×10^{12}	$\text{cm} \times \text{Hz}^{1/2} / \text{W}$

Relative Spectral Sensitivity ^{1) page 8}



Photocurrent / Open-Circuit Voltage ^{1) page 8}

$$I_P (V_R = 5 \text{ V}) / V_O = f(E_e)$$



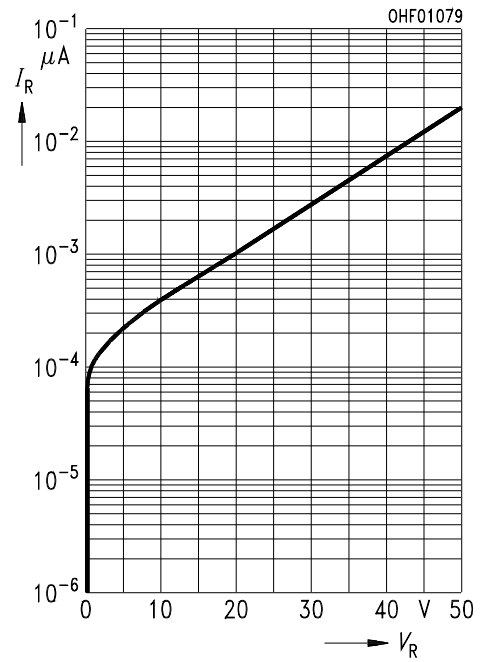
Power Consumption

$P_{tot} = f(T_A)$



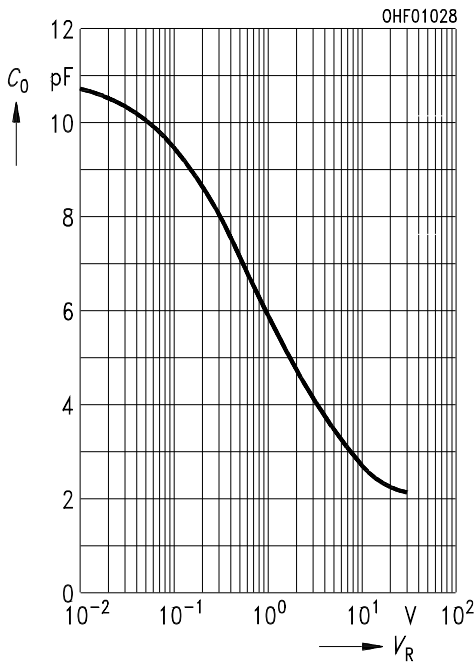
Dark Current ^{1) page 8}

$I_R = f(V_R), E = 0$



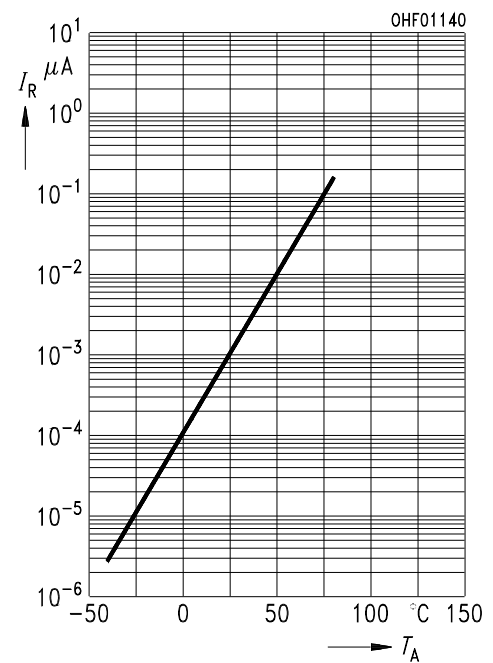
Capacitance ^{1) page 8}

$C = f(V_R), f = 1 \text{ MHz}, E = 0$



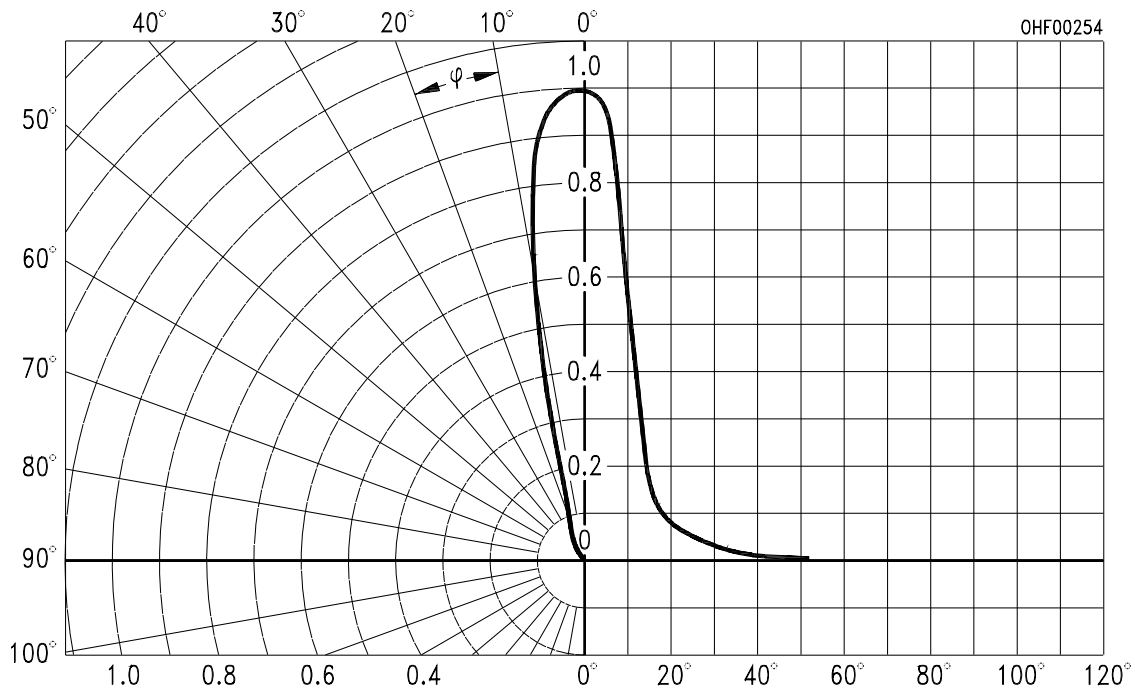
Dark Current ^{1) page 8}

$I_R = f(T_A), V_R = 20 \text{ V}, E = 0$

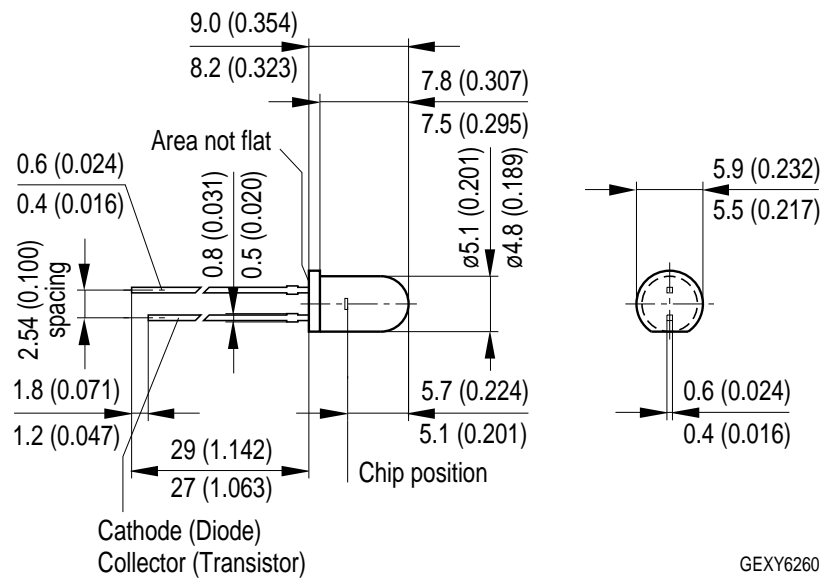


Directional Characteristics ^{1) page 8}

$S_{rel} = f(\phi)$



Package Outline



Dimensions in mm (inch).

Package

5mm Radial (T 1 3/4), Epoxy

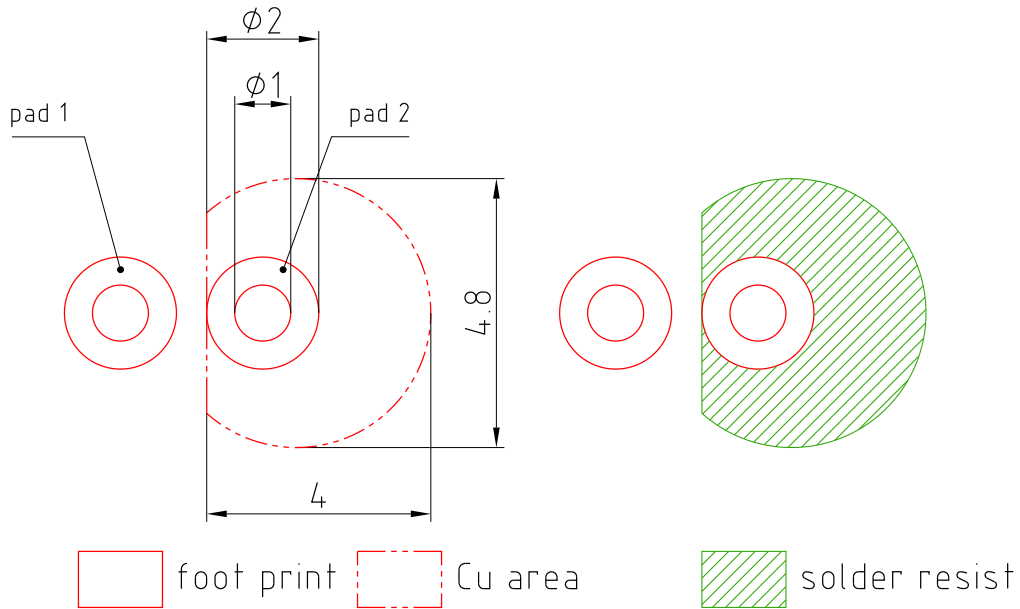
Approximate Weight:

0.4 g

Note

Packing information is available on the internet (online product catalog).

Recommended Solder Pad



Dimensions in mm.

E062.3010.188-01

Note:

pad 1: anode

TTW Soldering

IEC-61760-1 TTW

**Disclaimer**

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

Attention please!

The information describes the type of component and shall not be considered as assured characteristics.

Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.

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**) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.

Glossary

- ¹⁾ **Typical Values:** Due to the special conditions of the manufacturing processes of LED, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.

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Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

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